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FAIRCHILD

SEMICONDUCTOR®

FDS8880 N-Channel PowerTrench[®] MOSFET

30V, 11.6A, 10m Ω

Features

- r_{DS(on)} = 10mΩ, V_{GS} = 10V, I_D = 11.6A
- $r_{DS(on)} = 12m\Omega$, $V_{GS} = 4.5V$, $I_D = 10.7A$
- High performance trench technology for extremely low ^rDS(on)
- Low gate charge
- High power and current handling capability
- RoHS Compliant

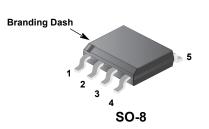


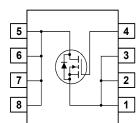
General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(on)}$ and fast switching speed.

Applications

DC/DC converters





April 2007

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Symbol	Parameter				Ratings			Units
V _{DSS}	Drain to Source Voltage			30			V	
V _{GS}	Gate to Source Voltage			±20			V	
	Drain Cur	Drain Current						
I_	Continuous (T _A = 25°C, V _{GS} = 10V, $R_{\theta JA}$ = 50°C/W)				11.6			Α
I _D	Continuous (T _A = 25°C, V _{GS} = 4.5V, $R_{\theta JA}$ = 50°C/W)				10.7			Α
	Pulsed					A		
E _{AS}	Single Pulse Avalanche Energy (Note 1)			82			mJ	
P _D	Power dissipation					2.5	W	
	Derate above 25°C			20 -55 to 150			mW/º	
T _J , T _{STG}	Operating and Storage Temperature					°C		
Therma	Chara	cteristics						
$R_{\theta JC}$	Thermal I	Resistance, Junction to Case	e (Note 2)			25		°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient (Note 2a)				50		°C/V	
R _{0JA}	Thermal I	Resistance, Junction to Ambi	ent (Note 2b)			125		°C/V
	e Marki	ng and Ordering l	nformatio	n				
Device N		Device	Package	Reel Size	Tape	Width	Qua	ntity
FDS8	-	FDS8880	SO-8	330mm	Tape Width 12mm		2500 units	
Symbol Off Chara	cteristic	Parameter S	Test	Conditions	Min	Тур	Max	Units
B _{VDSS}	1	Source Breakdown Voltage	I _D = 250μA,	V _{GS} = 0V	30	-	-	V
	Zoro Cot	Valtaga Drain Current	V _{DS} = 24V		-	-	1	
IDSS	Zero Gale	e Voltage Drain Current	$V_{GS} = 0V$	$T_{J} = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to S	ource Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Chara	cteristic	6						
V _{GS(TH)}		ource Threshold Voltage	V _{GS} = V _{DS} ,	Iр = 250µА	1.2	- 1	2.5	V
UU(III)			I _D = 11.6A, V		-	7.9	10.0	.
_	Ducks to C			V _{GS} = 4.5V	-	9.6	12.0	
r _{DS(on)}	Drain to S	Source On Resistance	I _D = 11.6A, Y	I _D = 11.6A, V _{GS} = 10V,		10 5	16.2	mΩ
			$T_{J} = 150^{\circ}C$	$T_{\rm J} = 150^{\rm o}{\rm C}$		12.5	16.3	
Dynamic	Characte	eristics						
C _{ISS}	Input Cap	acitance	$V_{-1} = 15V_{-1}$	$V_{ab} = 0 V_{ab}$	-	1235	-	pF
C _{OSS}		apacitance	──V _{DS} = 15V, V _{GS} = 0V, ──f = 1MHz		-	260	-	pF
C _{RSS}		Fransfer Capacitance			-	150	-	pF
R _G	Gate Res		V _{GS} = 0.5V,		0.6	2.5	4.3	Ω
Q _{g(TOT)}		e Charge at 10V	V_{GS} = 0V to	10V	-	23	30	nC
Q _{g(5)}		e Charge at 5V	V _{GS} = 0V to	5V V _{DD} = 15V	-	12	16	nC
Q _{g(TH)}		Gate Charge	$V_{GS} = 0V$ to	$I_D = 11.6A$ $I_V I_g = 1.0mA$	-	1.3	1.6	nC
Q _{gs}		ource Gate Charge		Ŭ.	-	3.3	-	nC
Q _{gs2}	Gate Cha	rge Threshold to Plateau			-	2.0	-	nC
Q _{gd}		rain "Miller" Charge				4.2		nC

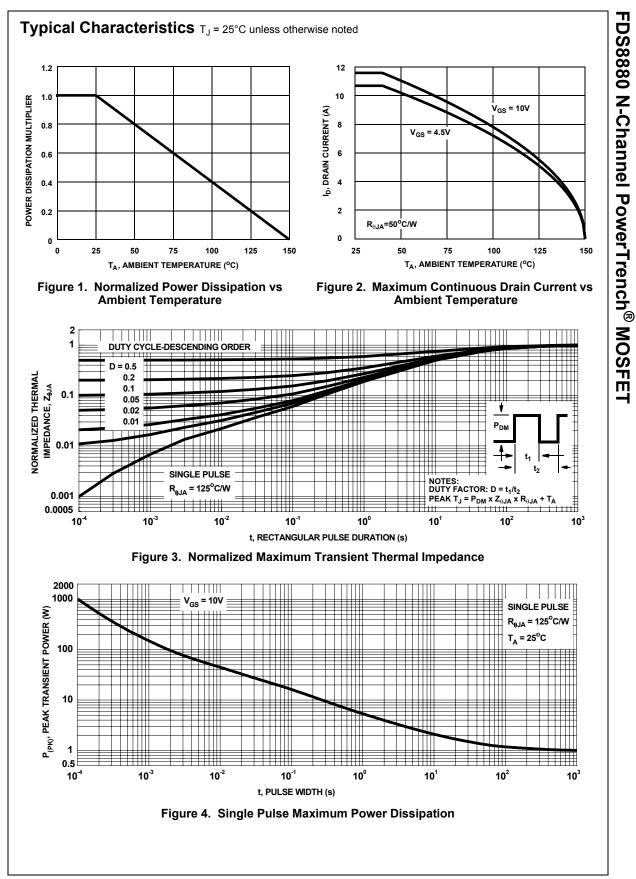
Switchir	Switching Characteristics (V _{GS} = 10V)							
t _{ON}	Turn-On Time		-	-	51	ns		
t _{d(ON)}	Turn-On Delay Time		-	7	-	ns		
t _r	Rise Time	$V_{DD} = 15V, I_D = 11.6A$ $V_{GS} = 10V, R_{GS} = 11\Omega$	-	27	-	ns		
t _{d(OFF)}	Turn-Off Delay Time		-	38	-	ns		
t _f	Fall Time		-	15	-	ns		
t _{OFF}	Turn-Off Time		-	-	80	ns		

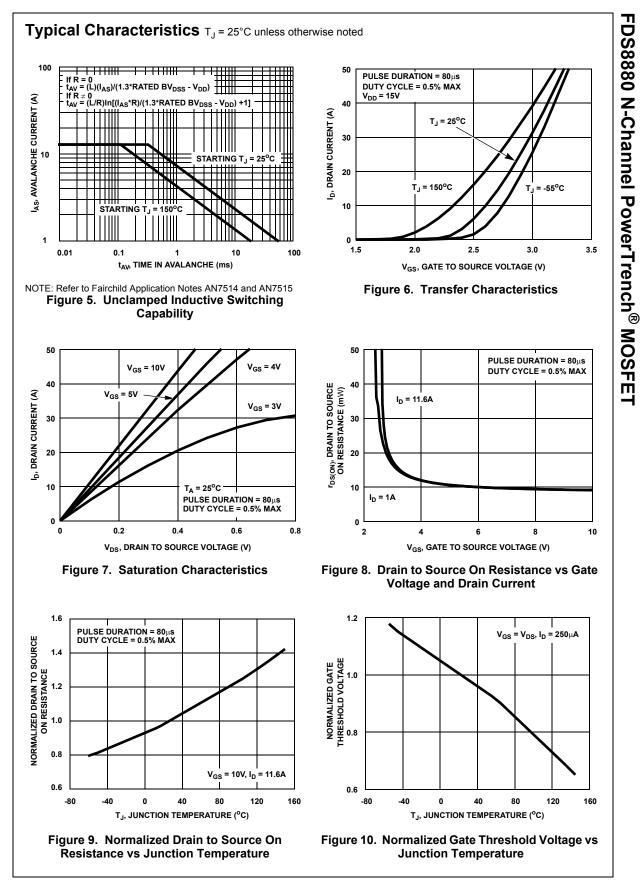
Drain-Source Diode Characteristics

V _{SD}	Source to Drain Diode Voltage	I _{SD} = 11.6A	-	-	1.25	V
		I _{SD} = 2.1A	-	-	1.0	V
t _{rr}	Reverse Recovery Time	I _{SD} = 11.6A, dI _{SD} /dt = 100A/μs	-	-	30	ns
Q _{RR}	Reverse Recovered Charge	I _{SD} = 11.6A, dI _{SD} /dt = 100A/μs	-	-	20	nC

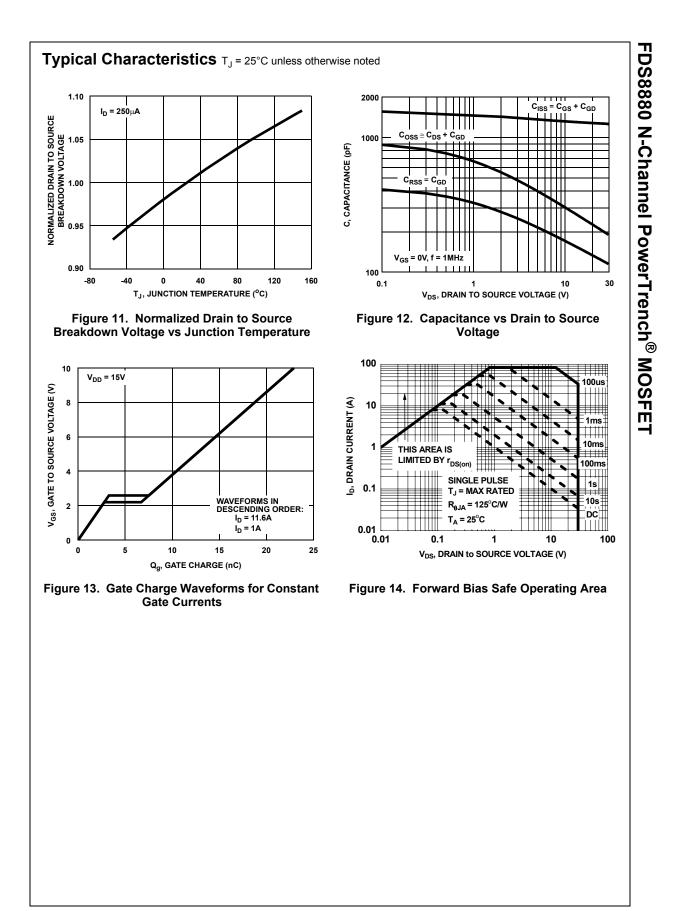
Notes:
1: Starting T_J = 25°C, L = 1mH, I_{AS} = 12.8A, V_{DD} = 30V, V_{GS} = 10V.
2: R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θJA} is determined by the user's board design.
a) 50°C/W when mounted on a 1in² pad of 2 oz copper.

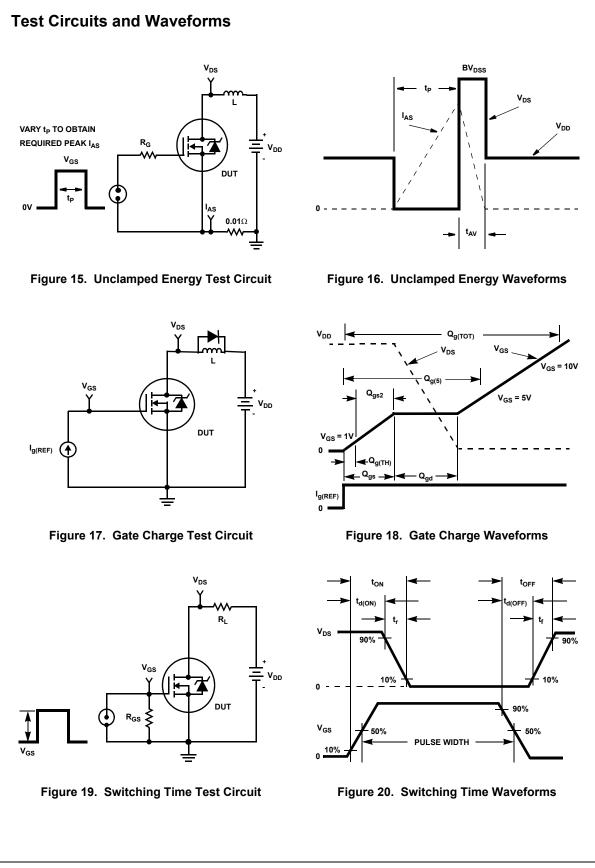
b) 125°C/W when mounted on a minimum pad.





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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the SO8 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient

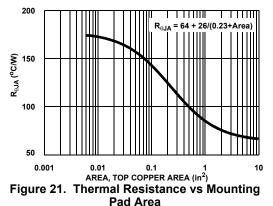
thermal impedance curve.

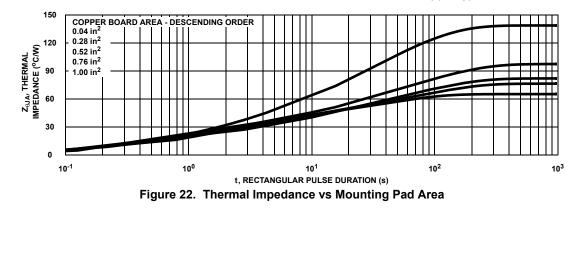
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2. The area, in square inches is the top copper area including the gate and source pads.

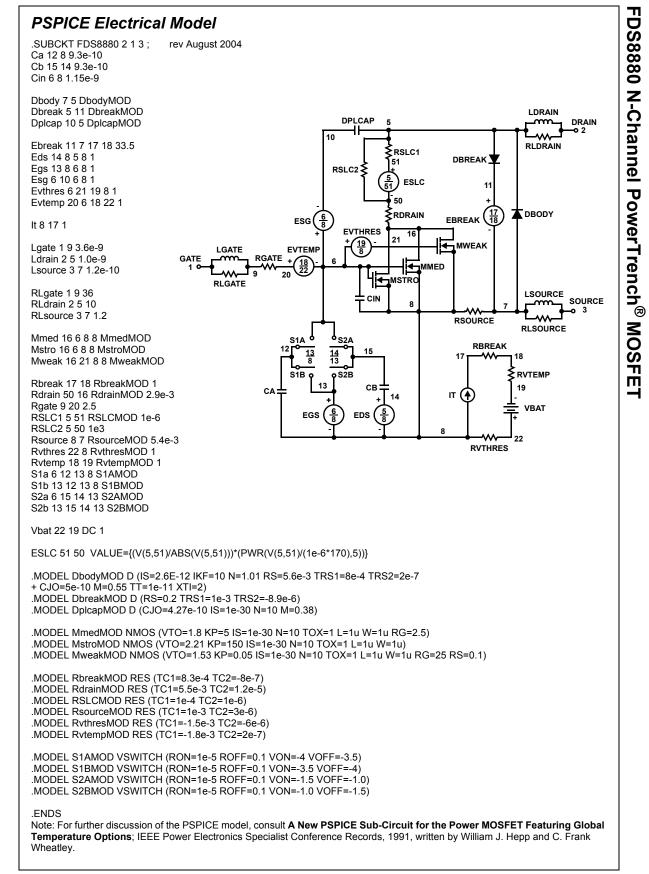
$$R_{\theta JA} = 64 + \frac{26}{0.23 + Area}$$
 (EQ. 2)

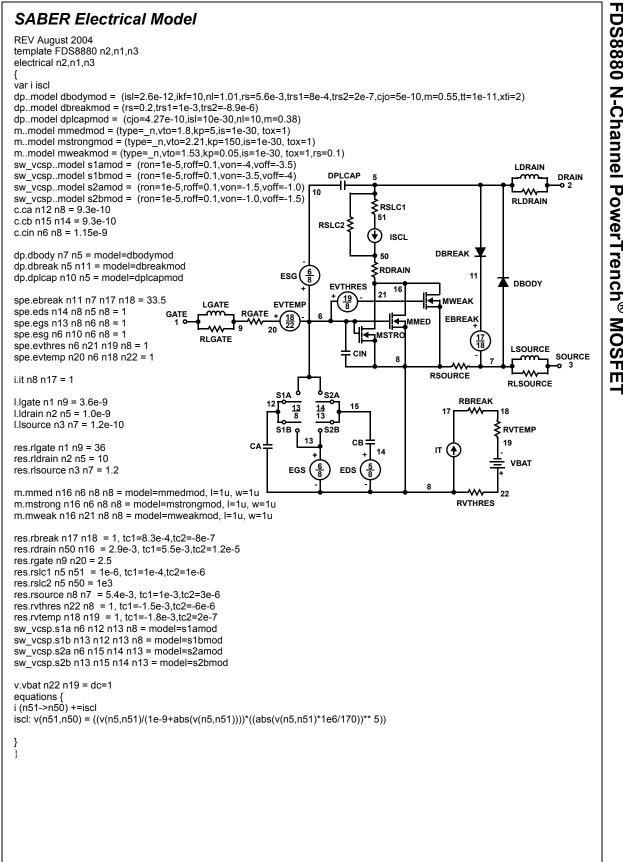
The transient thermal impedance (Z_{0JA}) is also effected by varied top copper board area. Figure 22 shows the effect of copper pad area on single pulse transient thermal impedance. Each trace represents a copper pad area in square inches corresponding to the descending list in the graph. Spice and SABER thermal models are provided for each of the listed pad areas.

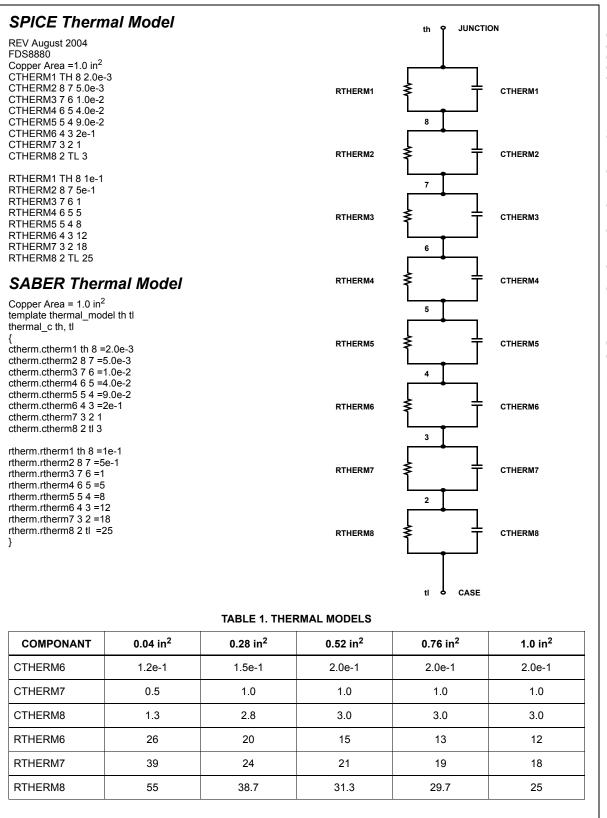
Copper pad area has no perceivable effect on transient thermal impedance for pulse widths less than 100ms. For pulse widths less than 100ms the transient thermal impedance is determined by the die and package. Therefore, CTHERM1 through CTHERM5 and RTHERM1 through RTHERM5 remain constant for each of the thermal models. A listing of the model component values is available in Table 1.











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